# 1N4001 THRN 1N4007

1.0 AMP SURFACE MOUNT SILICON RECTIFIERS

M1 THRN M7

### **FEATURES**

- \* Low forward voltage drop
- \* Low leakage current
- \* High reliability

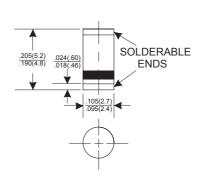
### **MECHANICAL DATA**

- \* Case: Molded plastic
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Metallurgically bonded construction
- \* Polarity: Color band denotes cathode end
- \* Mounting position: Any \* Weight: 0.015 grams

## VOLTAGE RANGE 50 to 1000 Volts CURRENT

SM-1

1.0 Ampere



Dimensions in inches and (millimeters)

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwies specified. Single phase half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

TYPE NUMBER	SM4001	SM4002	SM4003	SM4004	SM4005	SM4006	SM4007	UNITS
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current								
See Fig. 2		1.0						
Peak Forward Surge Current, 8.3 ms single half sine-wave								
superimposed on rated load (JEDEC method)		30						Α
Maximum Instantaneous Forward Voltage at 1.0A		1.1					V	
Maximum DC Reverse Current Ta=25 ℃		5.0						
at Rated DC Blocking Voltage Ta=100 ℃		50						
Typical Junction Capacitance (Note 1)		15						pF
Typical Thermal Resistance RθJA (Note 2)		50						°C/W
Operating and Storage Temperature Range TJ, TsTG		-65—+175						

### NOTES:

- 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
- 2. Thermal Resistance from Junction to Ambient.

### RATING AND CHARACTERISTIC CURVES (SM4001 THRU SM4007)

FIG.1-TYPICAL FORWARD

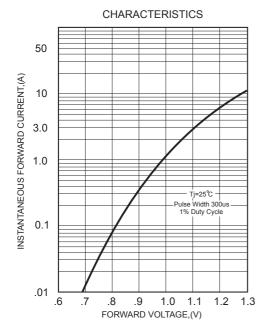


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

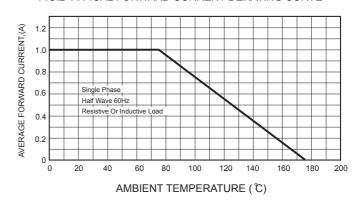


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

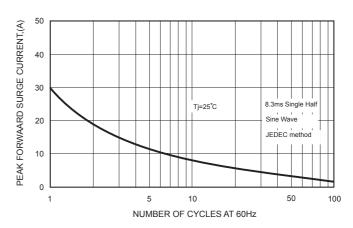


FIG.3 - TYPICAL REVERSE

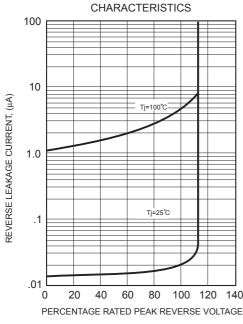


FIG.5-TYPICAL JUNCTION CAPACITANCE

